



flowPACK E1		600 V / 50 A
Features		
• Trenchstop™ IGBT3 technology • Standard industrial housing • Optimized $R_{th(j-s)}$ with Phase Change Material • Built-in NTC		
Target applications		
• Industrial Drives		
Types		
• 10-EZ066PA050SA-L855F38T • 10-E1066PA050SA-L855F38Z		
flow E1 12 mm housing		
	Press-fit pin Solder pin	
Schematic		

Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
Inverter Switch				
Collector-emitter voltage	V_{CES}		600	V
Collector current	I_C		50	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	150	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	95	W
Gate-emitter voltage	V_{GES}		± 20	V
Short circuit ratings	t_{SC}	$V_{GE} = 15\text{ V}$ $V_{cc} = 360\text{ V}$ $T_j = 150^\circ\text{C}$	6	μs
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$



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Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
Inverter Diode				
Peak repetitive reverse voltage	V_{RRM}		600	V
Continuous (direct) forward current	I_F	$T_j = T_{jmax}$	46	A
Repetitive peak forward current	I_{FRM}		100	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$	67	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Module Properties

General Properties				
Stray inductance	L_P		25	nH
Thermal Properties				
Storage temperature	T_{stg}		-40...+125	$^\circ\text{C}$
Operation temperature under switching condition	T_{op}		-40...($T_{jmax} - 25$)	$^\circ\text{C}$

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage*	$t_p = 2 \text{ s}$	6000	V
		AC Voltage	$t_p = 1 \text{ min}$	2500	V
Creepage distance				min. 12,7	mm
Clearance				8,62	mm
Comparative Tracking Index	CTI			≥ 600	

*100 % tested in production



Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
		V_{GE} [V]	V_{CE} [V]	I_c [A]	I_D [A]	T_j [°C]	Min	Typ	Max		
		V_{GS} [V]	V_{DS} [V]	I_F [A]	I_F [A]						

Inverter Switch

Static

Gate-emitter threshold voltage	$V_{GE(\text{th})}$	$V_{GE} = V_{CE}$			0,0008	25	5	5,8	6,5	V
Collector-emitter saturation voltage	$V_{CE\text{sat}}$		15		50	125 150	1,05	1,57 1,76 1,80	1,85	V
Collector-emitter cut-off current	I_{CES}		0	600		25			2,6	µA
Gate-emitter leakage current	I_{GES}		20	0		25			600	nA
Internal gate resistance	r_g							none		Ω
Input capacitance	C_{ies}	$f = 1 \text{ Mhz}$	0	25	25			3140		pF
Output capacitance	C_{oes}							200		
Reverse transfer capacitance	C_{res}							93		

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{\text{paste}} = 3,4 \text{ W/mK}$ (PSX)						1,00		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 8 \Omega$ $R_{goff} = 8 \Omega$	± 15	300	50	25 150		95 100		ns
Rise time	t_r					25 150		14 18		
Turn-off delay time	$t_{d(off)}$					25 150		161 184		
Fall time	t_f					25 150		109 131		
Turn-on energy (per pulse)*	E_{on}					25 150		0,675 1,02		
Turn-off energy (per pulse)*	E_{off}					25 150		1,30 1,76		

* $L_s = 14 \text{ nH}$



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

Inverter Diode

Static

Forward voltage	V_F				50	25 125 150		1,64 1,56 1,54	1,9	V
Reverse leakage current	I_R			600		25			27	μA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						1,41		K/W
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Dynamic

Peak recovery current	I_{RRM}	$di/dt = 3939 \text{ A/us}$ $di/dt = 3496 \text{ A/us}$	± 15	300	50	25 150		52 62		A
Reverse recovery time	t_{rr}					25 150		130 172		ns
Recovered charge	Q_r					25 150		2,29 4,37		μC
Reverse recovered energy	E_{rec}					25 150		0,515 0,92		mWs
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					25 150		3909 2375		A/ μs

Thermistor

Rated resistance	R					25		5		k Ω
Deviation of R_{100}	$\Delta R/R$	$R_{100} = 493 \Omega$				100	-5		+5	%
Power dissipation	P					25		245		mW
Power dissipation constant						25		1,4		mW/K
B-value	$B_{(25/50)}$	Tol. ±2 %				25		3375		K
B-value	$B_{(25/100)}$	Tol. ±2 %				25		3437		K
Vincotech NTC Reference									K	



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Inverter Switch Characteristics

figure 1.

Typical output characteristics

IGBT

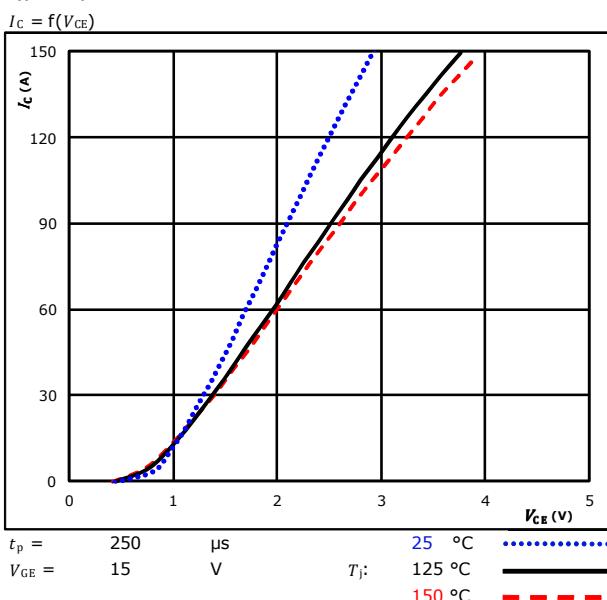


figure 2.

Typical output characteristics

IGBT

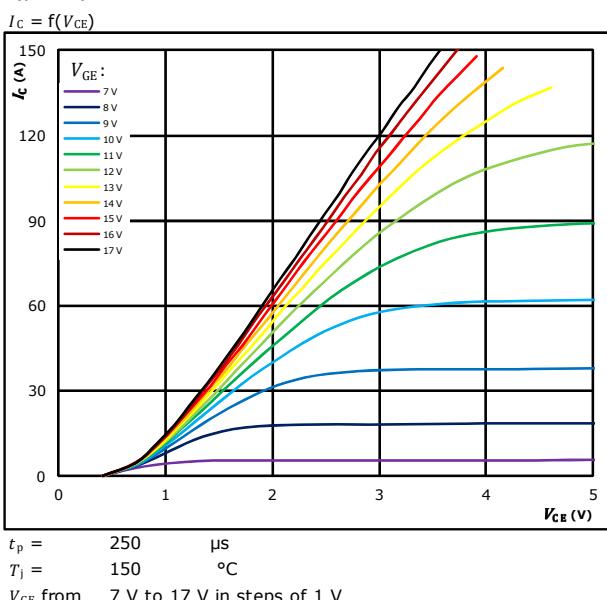


figure 3.

Typical transfer characteristics

IGBT

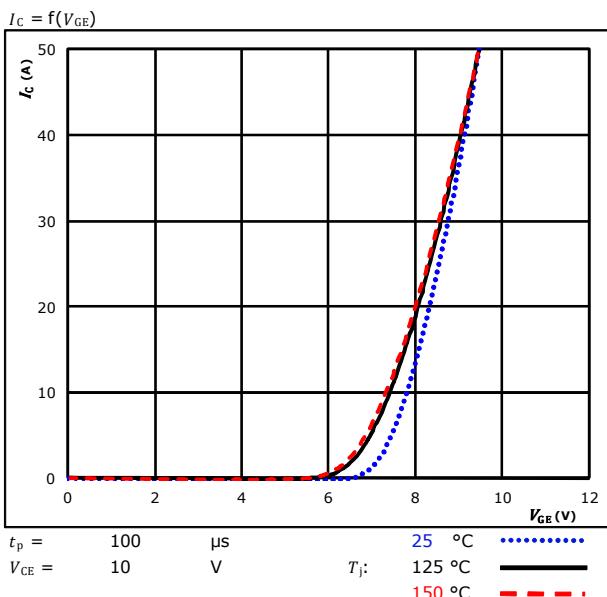
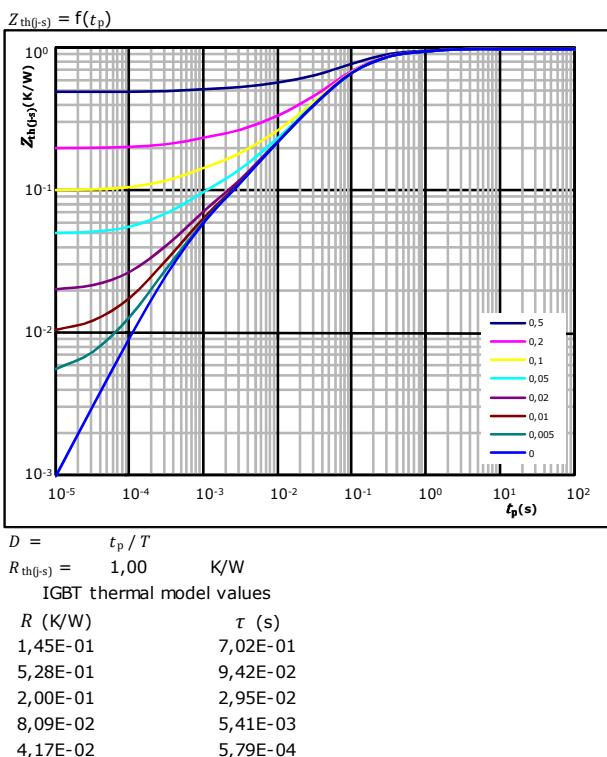


figure 4.

Transient thermal impedance as function of pulse duration

IGBT

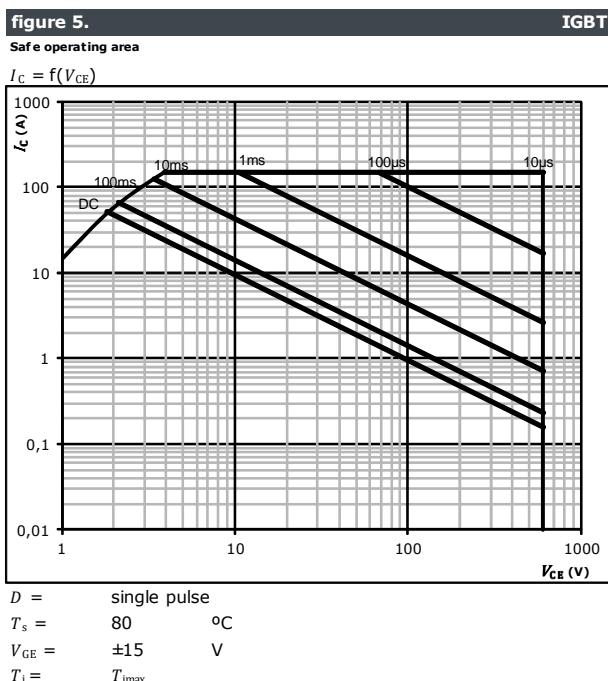




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Inverter Switch Characteristics

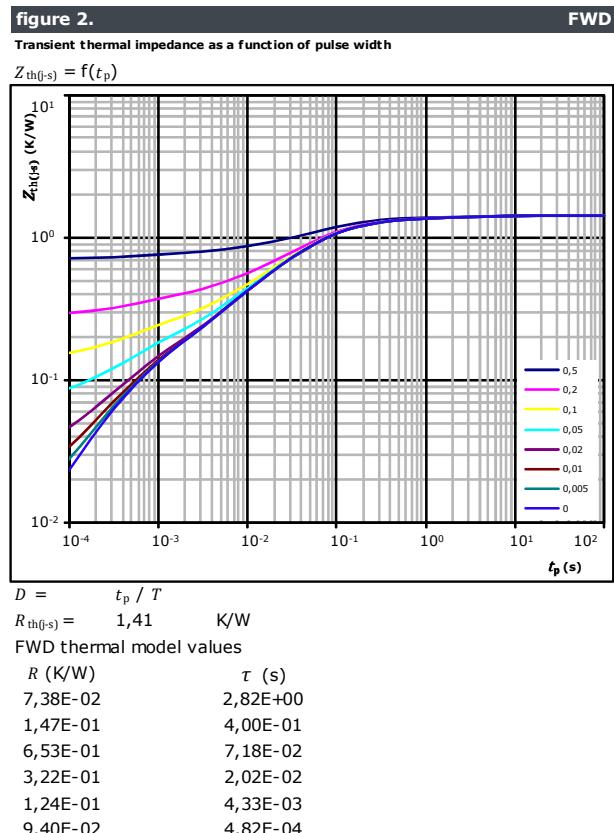
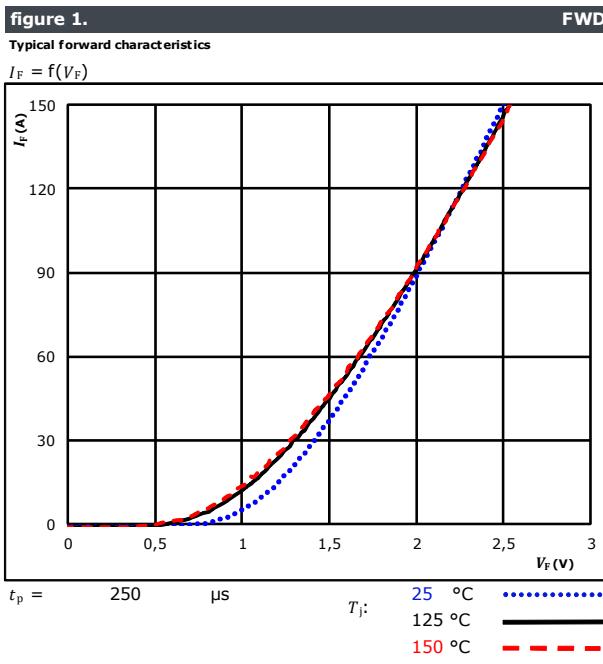




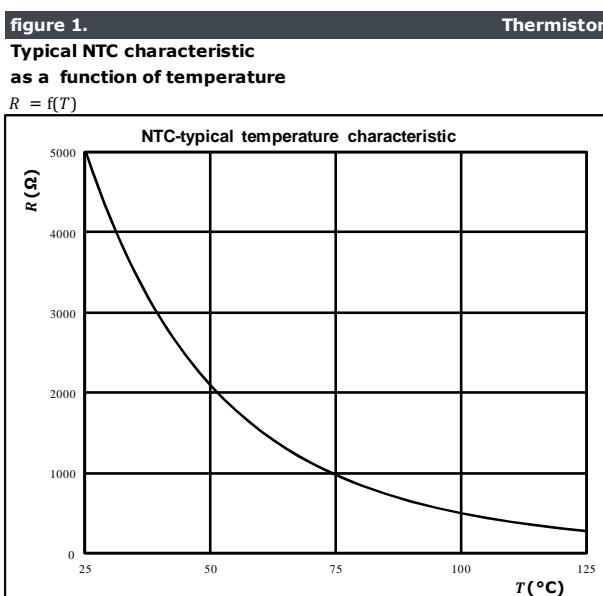
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Inverter Diode Characteristics



Thermistor Characteristics





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Inverter Switching Characteristics

figure 1.

Typical switching energy losses as a function of collector current

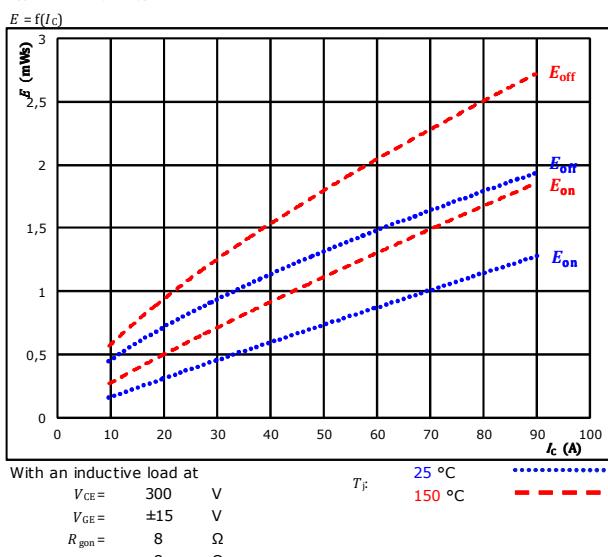


figure 2.

Typical switching energy losses as a function of gate resistor

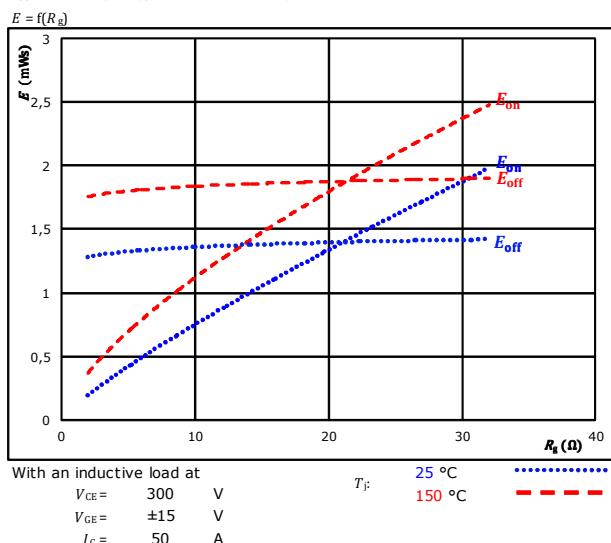


figure 3.

Typical reverse recovered energy loss as a function of collector current

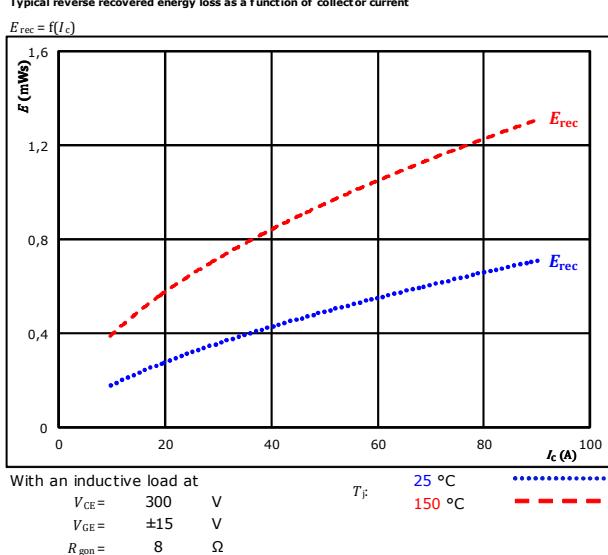
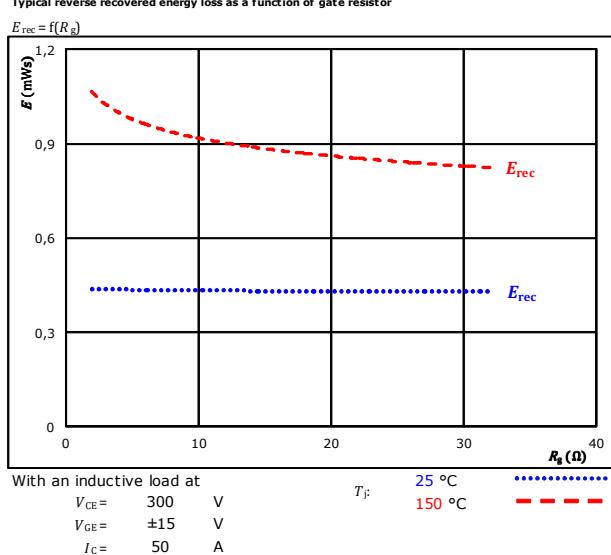


figure 4.

Typical reverse recovered energy loss as a function of gate resistor



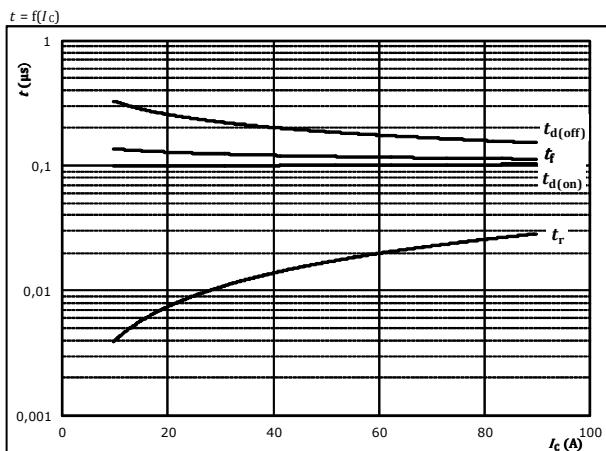


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Inverter Switching Characteristics

figure 5. IGBT

Typical switching times as a function of collector current

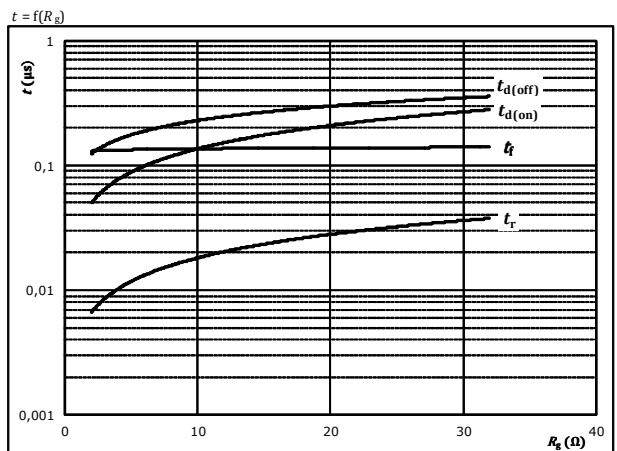


With an inductive load at

$T_j =$	150	°C
$V_{CE} =$	300	V
$V_{GE} =$	±15	V
$R_{gon} =$	8	Ω
$R_{goff} =$	8	Ω

figure 6. IGBT

Typical switching times as a function of gate resistor

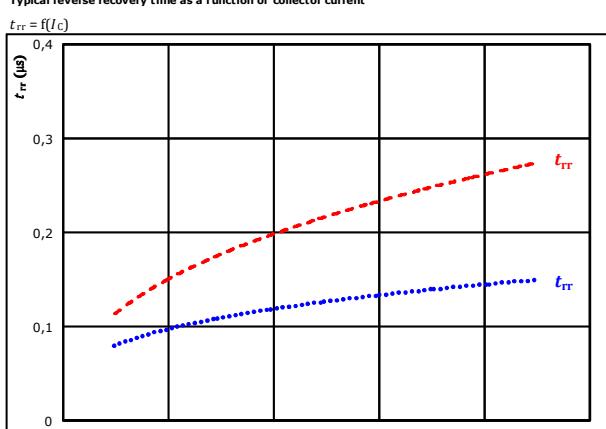


With an inductive load at

$T_j =$	150	°C
$V_{CE} =$	300	V
$V_{GE} =$	±15	V
$I_C =$	50	A

figure 7. FWD

Typical reverse recovery time as a function of collector current



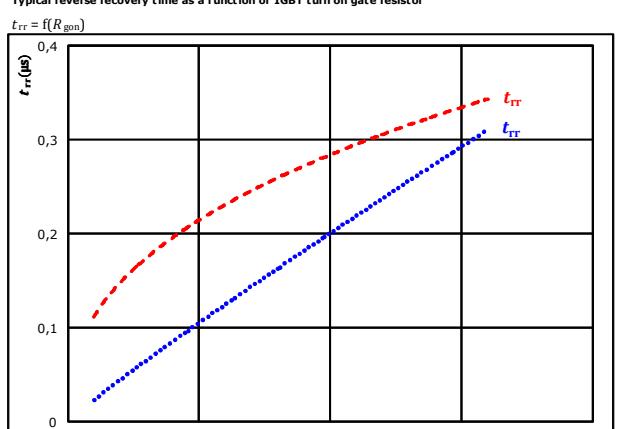
At $V_{CE} = 300$ V $T_j = 25$ °C $I_C = 50$ A

$V_{GE} = \pm 15$ V $T_j = 150$ °C $R_{gon} = 8$ Ω

$R_{goff} = 8$ Ω

figure 8. FWD

Typical reverse recovery time as a function of IGBT turn on gate resistor



At $V_{CE} = 300$ V $T_j = 25$ °C $I_C = 50$ A

$V_{GE} = \pm 15$ V $T_j = 150$ °C $R_{gon} = 8$ Ω

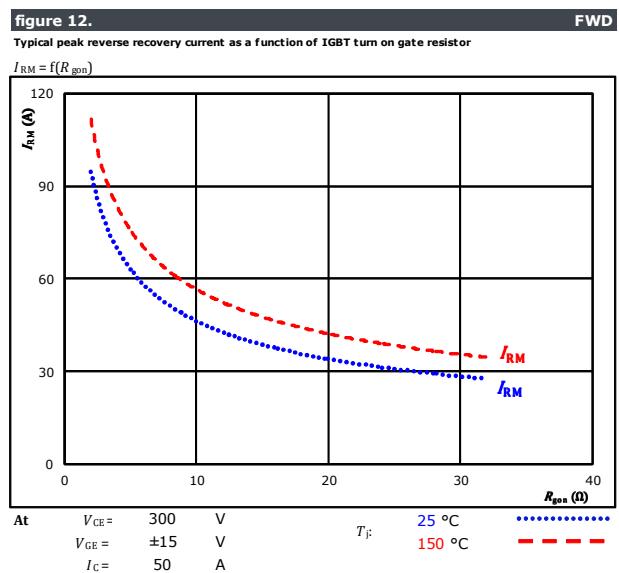
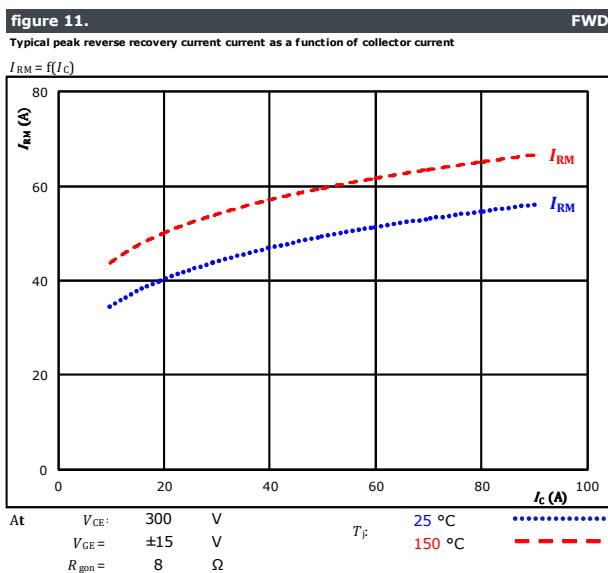
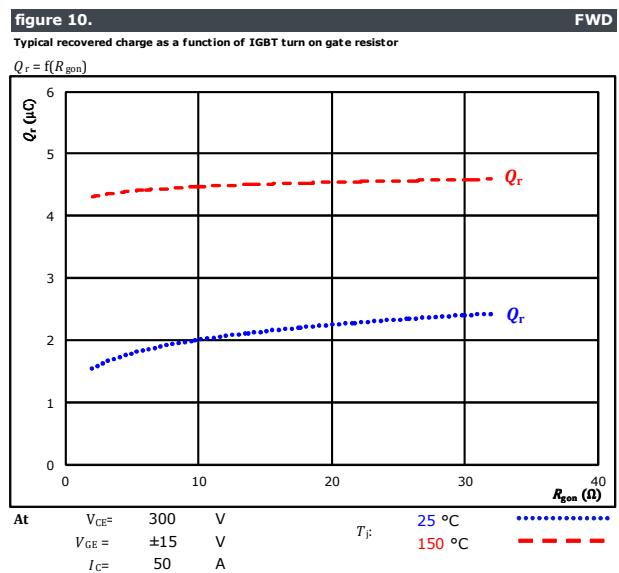
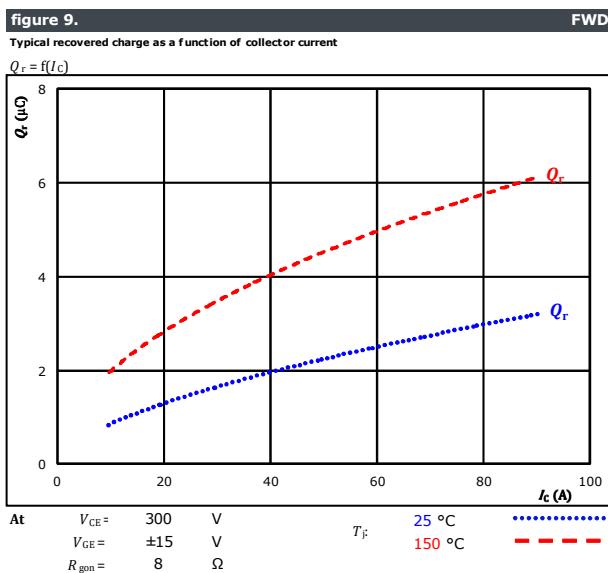
$R_{goff} = 8$ Ω



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Inverter Switching Characteristics





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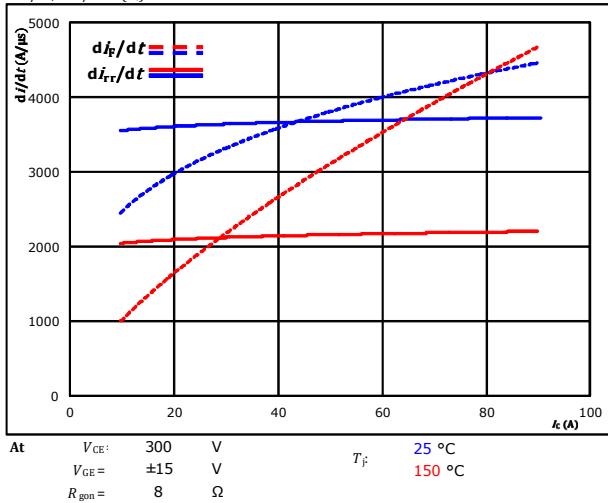
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Inverter Switching Characteristics

figure 13.

Typical rate of fall of forward and reverse recovery current as a function of collector current

$dI_F/dt, dI_{rr}/dt = f(I_C)$

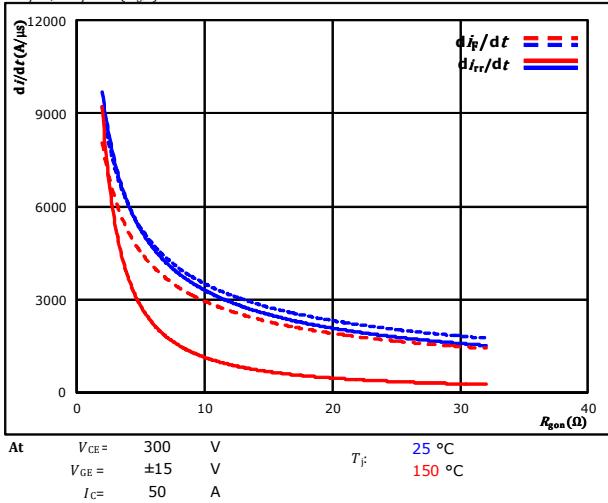


FWD

figure 14.

Typical rate of fall of forward and reverse recovery current as a function of IGBT turn on gate resistor

$dI_F/dt, dI_{rr}/dt = f(R_{gon})$

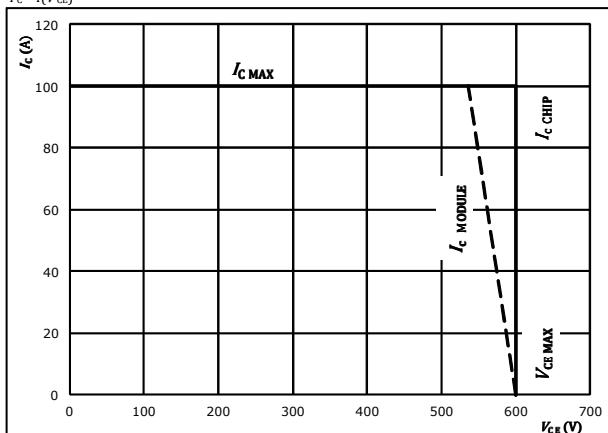


FWD

figure 15.

Reverse bias safe operating area

$I_C = f(V_{CE})$



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Inverter Switching Definitions

General conditions

T_j	=	125 °C
R_{gon}	=	8 Ω
R_{goff}	=	8 Ω

figure 1.

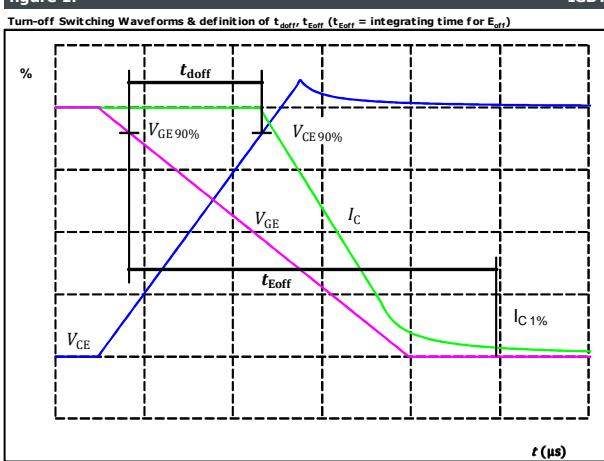


figure 2.

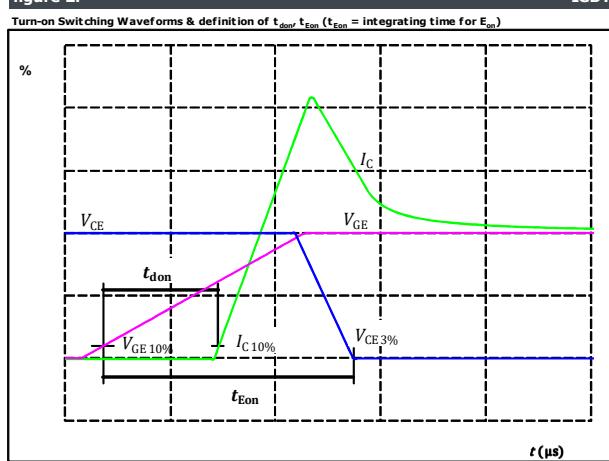


figure 3.

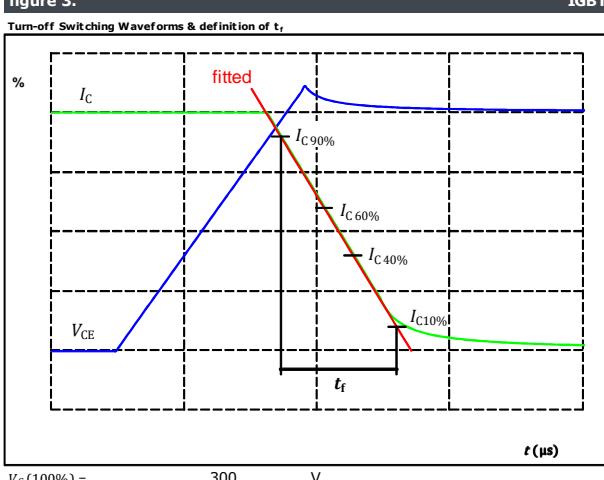
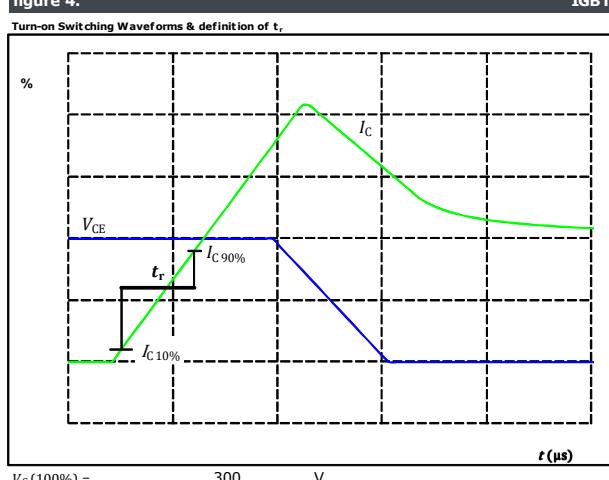


figure 4.





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Inverter Switching Characteristics

figure 5.

FWD

Turn-off Switching Waveforms & definition of t_{rr}

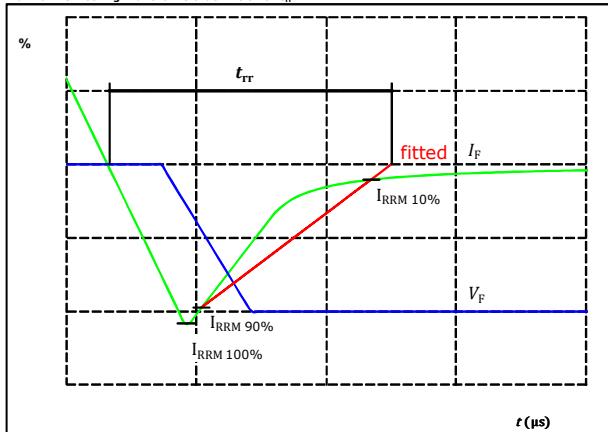
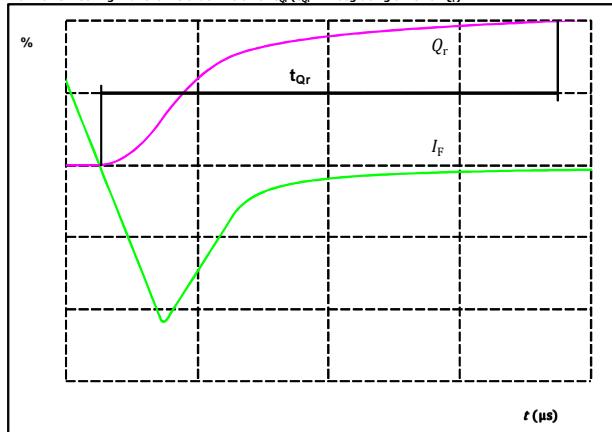


figure 6.

FWD

Turn-on Switching Waveforms & definition of t_{qr} (t_{qr} = integrating time for Q_r)





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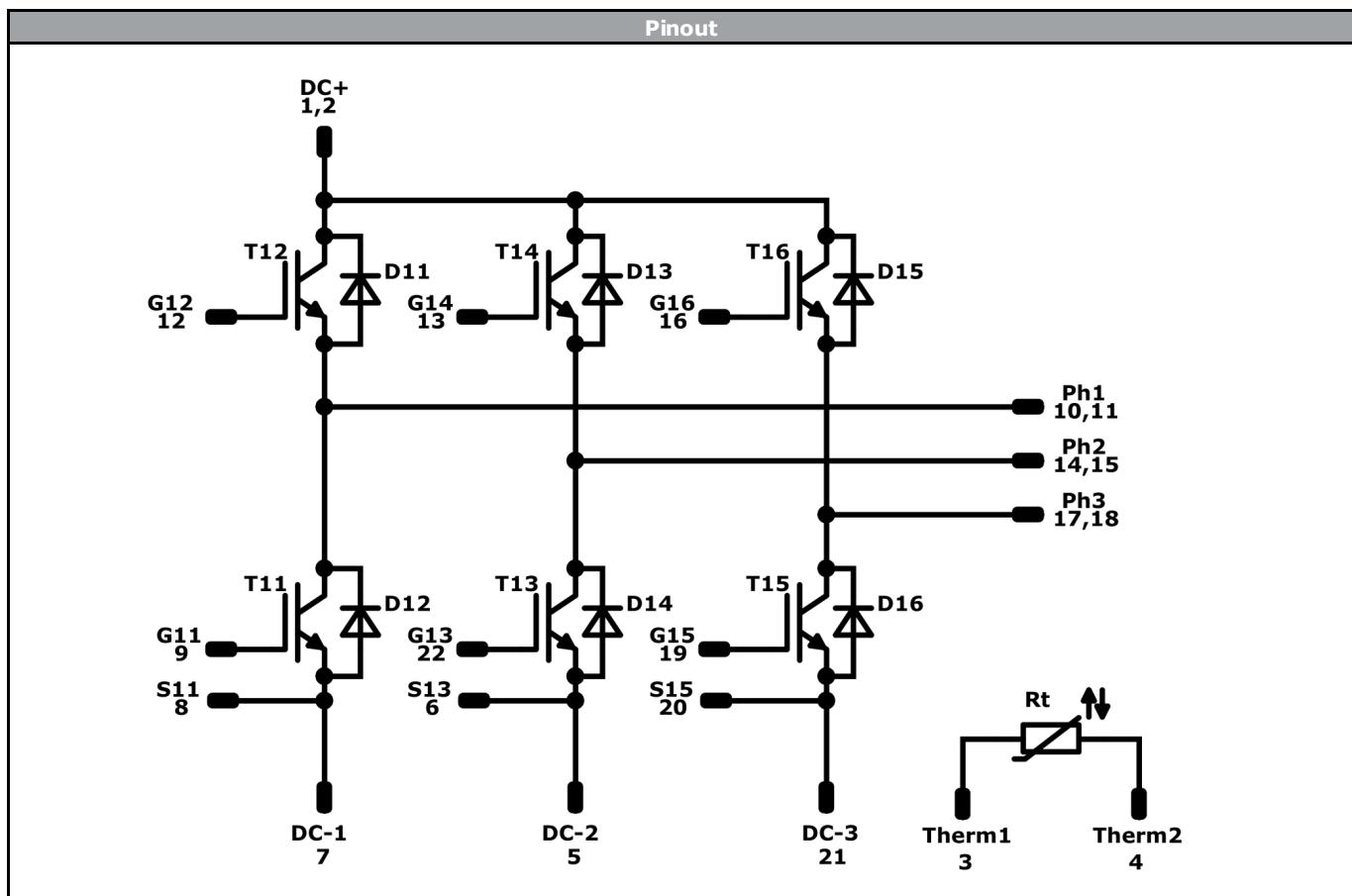
Ordering Code & Marking					
Version			Ordering Code		
without thermal paste 12 mm housing with press-fit pins			10-EZ066PA050SA-L855F38T		
with thermal paste 12 mm housing with press-fit pins			10-EZ066PA050SA-L855F38T-/3/		
without thermal paste 12 mm housing with solder pins			10-E1066PA050SA-L855F38Z		
with thermal paste 12 mm housing with solder pins			10-E1066PA050SA-L855F38Z-/3/		
NN-NNNNNNNNNNNNNN TTTTTTVV WWYY UL VIN LLLL SSSS			Text	Name	Date code
			NN-NNNNNNNNNNNNNN-TTTTTVW	WWYY	UL VIN
			Datamatrix	Type&Ver	Lot number
			TTTTTTVV	LLLLL	SSSS
					WWYY

Outline								
Pin table								
Pin	X	Y	Function					
1	12,8	9,6	DC+					
2	16	9,6	DC+					
3	22,4	9,6	Therm1					
4	25,6	9,6	Therm2					
5	32	9,6	DC-2					
6	32	6,4	S13					
7	32	3,2	DC-1					
8	32	0	S11					
9	28,8	0	G11					
10	6,4	0	Ph1					
11	3,2	0	Ph1					
12	0	0	G12					
13	0	6,4	G14					
14	0	16	Ph2					
15	0	19,2	Ph2					
16	0	25,6	G16					
17	3,2	25,6	Ph3					
18	6,4	25,6	Ph3					
19	28,8	25,6	G15					
20	32	25,6	S15					
21	32	22,4	DC-3					
22	32	16	G13					
Tolerance of pinpositions $\pm 0.4\text{mm}$ at the end of pins Dimension of coordinate axis is only offset without tolerance								



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Identification					
ID	Component	Voltage	Current	Function	Comment
T11, T12, T13, T14, T15, T16	IGBT	600 V	50 A	Inverter Switch	
D11, D12, D13, D14, D15, D16	FWD	600 V	50 A	Inverter Diode	
Rt	NTC			Thermistor	



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Packaging instruction			
Standard packaging quantity (SPQ) 100	>SPQ	Standard	<SPQ Sample

Handling instruction			
Handling instructions for <i>flow</i> E1 packages see vincotech.com website.			

Package data			
Package data for <i>flow</i> E1 packages see vincotech.com website.			

UL recognition and file number			
This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.			

Document No.:	Date:	Modification:	Pages
10-Ex066PA050SA-L855F38x-D2-14	26 Oct. 2018	Added Z option to ordering options	All

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.